<u>MOSFET</u> – Power, Single, N-Channel 40 V, 0.7 mΩ, 362 A

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	40	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain	Steady	$T_{C} = 25^{\circ}C$	۱ _D	362	А
Current $R_{\theta JC}$ (Notes 1, 3)		T _C = 100°C		256	
Power Dissipation	State	$T_{C} = 25^{\circ}C$	PD	179	W
R _{θJC} (Note 1)		T _C = 100°C		90	
Continuous Drain		T _A = 25°C	۱ _D	53	А
Current R _{θJA} (Notes 1, 2, 3)	Steady State	T _A = 100°C		38	
Power Dissipation		T _A = 25°C	PD	3.9	W
$R_{\theta JA}$ (Notes 1, 2)		T _A = 100°C		1.9	
Pulsed Drain Current	T _A = 25	°C, t _p = 10 μs	I _{DM}	900	А
Operating Junction and Storage Temperature Range			T _J , T _{stg}	–55 to +175	°C
Source Current (Body Diode)			I _S	149	А
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 32.5 A)			E _{AS}	498	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State	$R_{\theta JC}$	0.84	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	38.7	

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

2. Surface-mounted on FR4 board using a 650 $\rm mm^2,$ 2 oz. Cu pad.

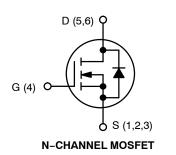
3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

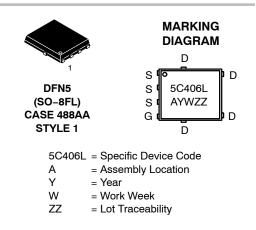


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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
40 V	$0.7~\mathrm{m}\Omega$ @ 10 V	362 A
40 V	1.1 mΩ @ 4.5 V	302 A





ORDERING INFORMATION

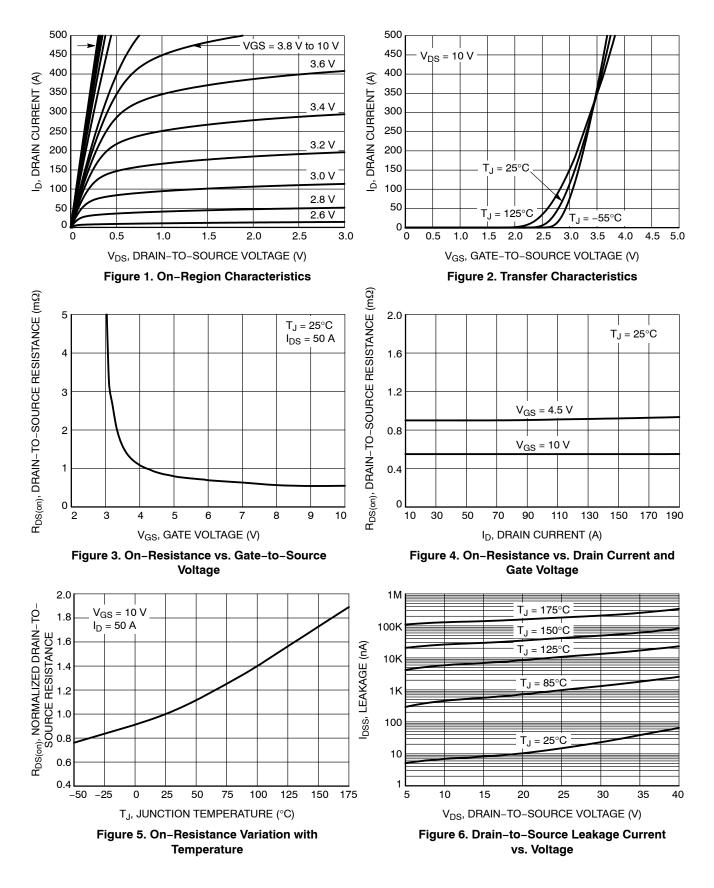
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

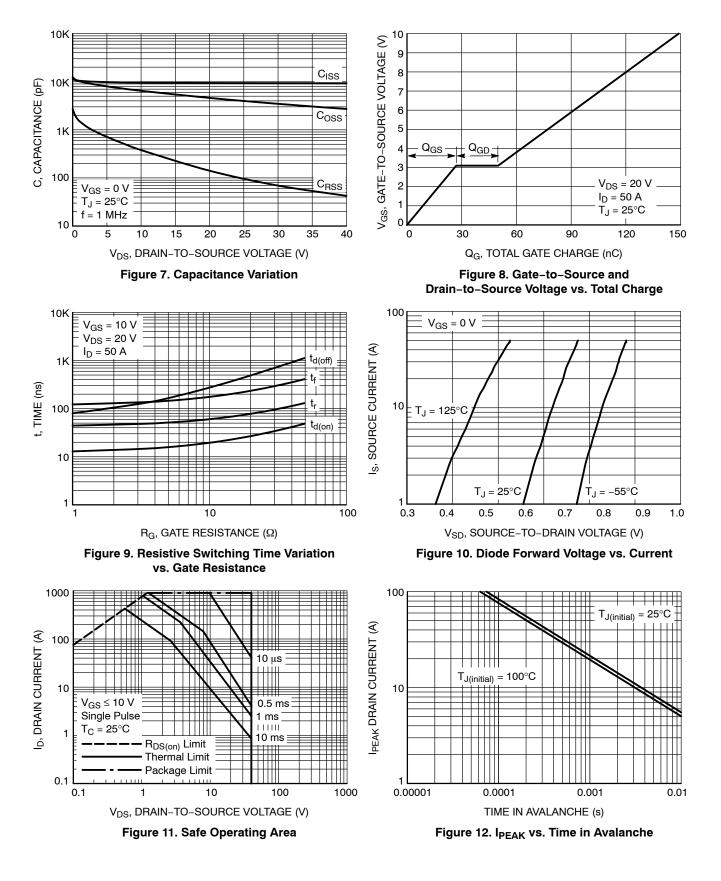
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS	•			-		-	-
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J				16		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V,$	T _J = 25 °C			10	μΑ
		V _{DS} = 40 V	T _J = 125°C			250	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V				100	nA
ON CHARACTERISTICS (Note 4)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = 280 \ \mu A$		1.2		2.0	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-5.7		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 50 A		0.55	0.7	_
		V _{GS} = 4.5 V	I _D = 50 A		0.90	1.1	mΩ
Forward Transconductance	9 _{FS}	V _{DS} =15 V, I _E	₎ = 50 A		215		S
CHARGES, CAPACITANCES & GATE RE	SISTANCE						
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}, V_{DS} = 20 \text{ V}$ $V_{GS} = 10 \text{ V}, V_{DS} = 20 \text{ V}; \text{ I}_{D} = 50 \text{ A}$			9400		pF
Output Capacitance	C _{OSS}				4600		
Reverse Transfer Capacitance	C _{RSS}				140		
Total Gate Charge	Q _{G(TOT)}				149		
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 10 V, V _{DS} = 20 V; I _D = 50 A			15.1		
Gate-to-Source Charge	Q _{GS}				27		
Gate-to-Drain Charge	Q _{GD}				22		
Plateau Voltage	V _{GP}				3.1		V
SWITCHING CHARACTERISTICS (Note 5	5)						
Turn-On Delay Time	t _{d(ON)}	V_{GS} = 10 V, V_{DS} = 20 V, I_{D} = 50 A, R_{G} = 2.5 Ω			14		- ns
Rise Time	tr				47		
Turn-Off Delay Time	t _{d(OFF)}				112		
Fall Time	t _f				131		
DRAIN-SOURCE DIODE CHARACTERIS	TICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V, I _S = 50 A	T _J = 25°C		0.78	1.2	v
			T _J = 125°C		0.64		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dIS/dt = 100 A/μs, I _S = 50 A			93		ns
Charge Time	ta				44		
Discharge Time	t _b				50		
Reverse Recovery Charge	Q _{RR}				174		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
4. Pulse Test: pulse width ≤ 300 µs, duty cycle ≤ 2%.
5. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

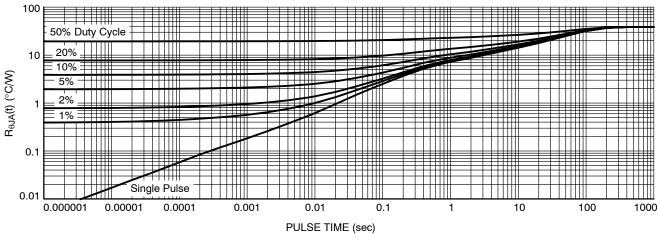


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMFS5C406NLT1G	5C406L	DFN5 (Pb–Free)	1500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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